

### FEATURES

**Low supply current: 250  $\mu$ A max**  
**Very low input bias current: 1 pA max**  
**Low offset voltage: 750  $\mu$ V max**  
**Single-supply operation: 5 V to 26 V**  
**Dual-supply operation:  $\pm 2.5$  V to  $\pm 13$  V**  
**Rail-to-rail output**  
**Unity gain stable**  
**No phase reversal**  
**SC70 package**

### APPLICATIONS

**Line-/battery-powered instruments**  
**Photodiode amplifiers**  
**Precision current sensing**  
**Medical instrumentation**  
**Industrial controls**  
**Precision filters**  
**Portable audio**  
**ATE**

### GENERAL DESCRIPTION

The AD8641/AD8642 are low power, precision JFET input amplifiers featuring extremely low input bias current and rail-to-rail output. The ability to swing nearly rail-to-rail at the input and rail-to-rail at the output enables designers to buffer CMOS DACs, ASICs, and other wide output swing devices in single-supply systems. The outputs remain stable with capacitive loads of more than 500 pF.

#### Rev. A

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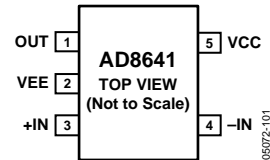


Figure 1. 5-Lead SC70 (KS-5)

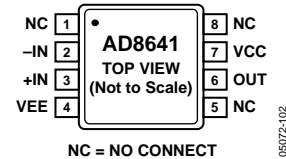


Figure 2. 8-Lead SOIC (R-8)

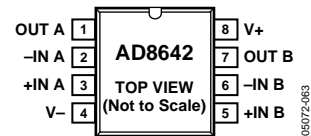


Figure 3. 8-Lead SOIC (R-8)

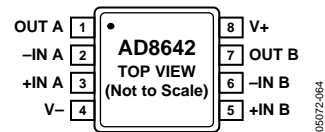


Figure 4. 8-Lead MSOP (RM-8)

The AD8641/AD8642 are suitable for applications utilizing multichannel boards that require low power to manage heat. Other applications include photodiodes, ATE reference level drivers, battery management, and industrial controls.

The AD8641/AD8642 are fully specified over the extended industrial temperature range of  $-40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$ . The AD8641 is available in 5-lead SC70 and 8-lead SOIC lead-free packages. The AD8642 is available in 8-lead MSOP and 8-lead SOIC lead-free packages.

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Outline Dimensions ..... 13  
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**REVISION HISTORY**

**3/05—Rev. 0 to Rev. A**

Added AD8642 ..... Universal  
Changes to General Description ..... 1  
Added Figure 3 and Figure 4..... 1  
Changes to Specifications ..... 3  
Changes to Absolute Maximum Ratings ..... 5  
Changes to Figure 22..... 8  
Changes to Figure 23..... 9  
Changes to Figure 41 ..... 12  
Updated Outline Dimensions ..... 13  
Changes to Ordering Guide ..... 14

**10/04—Initial Version: Revision 0**

## SPECIFICATIONS

### ELECTRICAL CHARACTERISTICS

@  $V_S = 5.0\text{ V}$ ,  $V_{CM} = 2.5\text{ V}$ ,  $T_A = 25^\circ\text{C}$ , unless otherwise noted.

Table 1.

| Parameter                     | Symbol                   | Conditions                                                                                                                | Min  | Typ     | Max  | Unit                         |
|-------------------------------|--------------------------|---------------------------------------------------------------------------------------------------------------------------|------|---------|------|------------------------------|
| <b>INPUT CHARACTERISTICS</b>  |                          |                                                                                                                           |      |         |      |                              |
| Offset Voltage                | $V_{OS}$                 | $-40^\circ\text{C} < T_A < +85^\circ\text{C}$<br>$+85^\circ\text{C} < T_A < +125^\circ\text{C}$ , $V_{CM} = 1.5\text{ V}$ |      | 50      | 750  | $\mu\text{V}$<br>mV          |
| Input Bias Current            | $I_B$                    | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                                            |      | 0.25    | 1    | pA                           |
| Input Offset Current          | $I_{OS}$                 | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                                            |      |         | 180  | pA                           |
| Input Voltage Range           |                          | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                                            | 0    |         | 3    | V                            |
| Common-Mode Rejection Ratio   | CMRR                     | $V_{CM} = 0\text{ V to } 2.5\text{ V}$                                                                                    | 74   | 93      |      | dB                           |
| Large Signal Voltage Gain     | $A_{VO}$                 | $R_L = 10\text{ k}\Omega$ , $V_O = 0.5\text{ to } 4.5\text{ V}$                                                           | 80   | 140     |      | V/mV                         |
| Offset Voltage Drift          | $\Delta V_{OS}/\Delta T$ | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                                            |      | 2.5     |      | $\mu\text{V}/^\circ\text{C}$ |
| <b>OUTPUT CHARACTERISTICS</b> |                          |                                                                                                                           |      |         |      |                              |
| Output Voltage High           | $V_{OH}$                 | $I_L = 1\text{ mA}$ , $-40^\circ\text{C to } +125^\circ\text{C}$                                                          | 4.95 |         |      | V                            |
| Output Voltage Low            | $V_{OL}$                 | $I_L = 1\text{ mA}$ , $-40^\circ\text{C to } +125^\circ\text{C}$                                                          | 4.94 |         | 0.05 | V                            |
| Output Current                | $I_{OUT}$                |                                                                                                                           |      | 0.01    | 0.05 | V                            |
|                               |                          |                                                                                                                           |      | $\pm 6$ |      | mA                           |
| <b>POWER SUPPLY</b>           |                          |                                                                                                                           |      |         |      |                              |
| Power Supply Rejection Ratio  | PSRR                     | $V_S = 5\text{ V to } 26\text{ V}$                                                                                        | 90   | 107     |      | dB                           |
| Supply Current/Amplifier      | $I_{SY}$                 | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                                            |      | 195     | 250  | $\mu\text{A}$                |
|                               |                          |                                                                                                                           |      |         | 270  | $\mu\text{A}$                |
| <b>DYNAMIC PERFORMANCE</b>    |                          |                                                                                                                           |      |         |      |                              |
| Slew Rate                     | SR                       |                                                                                                                           |      | 2       |      | V/ $\mu\text{s}$             |
| Gain Bandwidth Product        | GBP                      |                                                                                                                           |      | 3       |      | MHz                          |
| Phase Margin                  | $\phi_O$                 |                                                                                                                           |      | 50      |      | Degrees                      |
| <b>NOISE PERFORMANCE</b>      |                          |                                                                                                                           |      |         |      |                              |
| Voltage Noise                 | $e_N$ p-p                | $f = 0.1\text{ Hz to } 10\text{ Hz}$                                                                                      |      | 4.0     |      | $\mu\text{V p-p}$            |
| Voltage Noise Density         | $e_N$                    | $f = 1\text{ kHz}$                                                                                                        |      | 28.5    |      | nV/ $\sqrt{\text{Hz}}$       |
| Current Noise Density         | $i_N$                    | $f = 1\text{ kHz}$                                                                                                        |      | 0.5     |      | fA/ $\sqrt{\text{Hz}}$       |

# AD8641/AD8642

@  $V_S = \pm 13$  V,  $V_{CM} = 0$  V,  $T_A = 25^\circ\text{C}$ , unless otherwise noted.

**Table 2.**

| Parameter                     | Symbol                   | Conditions                                                | Min    | Typ      | Max    | Unit                   |
|-------------------------------|--------------------------|-----------------------------------------------------------|--------|----------|--------|------------------------|
| <b>INPUT CHARACTERISTICS</b>  |                          |                                                           |        |          |        |                        |
| Offset Voltage                | $V_{OS}$                 | $-40^\circ < T_A < +125^\circ\text{C}$                    |        | 70       | 750    | $\mu\text{V}$          |
| Input Bias Current            | $I_B$                    | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$            |        | 0.25     | 1      | pA                     |
| Input Offset Current          | $I_{OS}$                 | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$            |        |          | 260    | pA                     |
| Input Voltage Range           |                          | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$            |        |          | 65     | pA                     |
| Common-Mode Rejection Ratio   | CMRR                     | $V_{CM} = -13$ V to $+10$ V                               | -13    |          | +10    | V                      |
| Large Signal Voltage Gain     | $A_{VO}$                 | $R_L = 10$ k $\Omega$ , $V_O = -11$ V to $+11$ V          | 90     | 107      |        | dB                     |
| Offset Voltage Drift          | $\Delta V_{OS}/\Delta T$ | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$            | 215    | 290      |        | V/mV                   |
| <b>OUTPUT CHARACTERISTICS</b> |                          |                                                           |        |          |        |                        |
| Output Voltage High           | $V_{OH}$                 | $I_L = 1$ mA, $-40^\circ\text{C}$ to $+125^\circ\text{C}$ | +12.95 |          |        | V                      |
| Output Voltage Low            | $V_{OL}$                 | $I_L = 1$ mA, $-40^\circ\text{C}$ to $+125^\circ\text{C}$ | +12.94 |          | -12.95 | V                      |
| Output Current                | $I_{OUT}$                |                                                           |        | $\pm 12$ | -12.94 | V                      |
| <b>POWER SUPPLY</b>           |                          |                                                           |        |          |        |                        |
| Power Supply Rejection Ratio  | PSRR                     | $V_S = \pm 2.5$ V to $\pm 13$ V                           | 90     | 107      |        | dB                     |
| Supply Current/Amplifier      | $I_{SY}$                 | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$            |        | 200      | 290    | $\mu\text{A}$          |
| <b>DYNAMIC PERFORMANCE</b>    |                          |                                                           |        |          |        |                        |
| Slew Rate                     | SR                       |                                                           |        | 3        |        | V/ $\mu\text{s}$       |
| Gain Bandwidth Product        | GBP                      |                                                           |        | 3.5      |        | MHz                    |
| Phase Margin                  | $\phi_o$                 |                                                           |        | 60       |        | Degrees                |
| <b>NOISE PERFORMANCE</b>      |                          |                                                           |        |          |        |                        |
| Voltage Noise                 | $e_N$ p-p                | $f = 0.1$ Hz to $10$ Hz                                   |        | 4.2      |        | $\mu\text{V}$ p-p      |
| Voltage Noise Density         | $e_N$                    | $f = 1$ kHz                                               |        | 27.5     |        | nV/ $\sqrt{\text{Hz}}$ |
| Current Noise Density         | $i_N$                    | $f = 1$ kHz                                               |        | 0.5      |        | fA/ $\sqrt{\text{Hz}}$ |

## ABSOLUTE MAXIMUM RATINGS

Table 3.<sup>1</sup>

| Parameter                                  | Rating          |
|--------------------------------------------|-----------------|
| Supply Voltage                             | 27.3 V          |
| Input Voltage                              | VS- to VS+      |
| Differential Input Voltage                 | ±Supply Voltage |
| Output Short-Circuit Duration              | Indefinite      |
| Storage Temperature Range                  |                 |
| KS-5, R-8, RM-8 Packages                   | -65°C to +150°C |
| Operating Temperature Range                | -40°C to +125°C |
| Junction Temperature Range                 |                 |
| KS-5, R-8, RM-8 Packages                   | -65°C to +150°C |
| Lead Temperature Range (Soldering, 60 Sec) | 300°C           |

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those listed in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### ESD CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although this product features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



Table 4.

| Package Type       | $\theta_{JA}^2$ | $\theta_{JC}$ | Unit |
|--------------------|-----------------|---------------|------|
| 5-Lead SC70 (KS-5) | 331.4           | 223.9         | °C/W |
| 8-Lead SOIC (R-8)  | 157             | 56            | °C/W |
| 8-Lead MSOP (RM-8) | 206             | 44            | °C/W |

<sup>1</sup> Absolute maximum ratings apply at 25°C, unless otherwise noted.

<sup>2</sup>  $\theta_{JA}$  is specified for the worst-case conditions, i.e.,  $\theta_{JA}$  is specified for devices soldered on circuit boards for surface-mounted packages.

TYPICAL PERFORMANCE CHARACTERISTICS

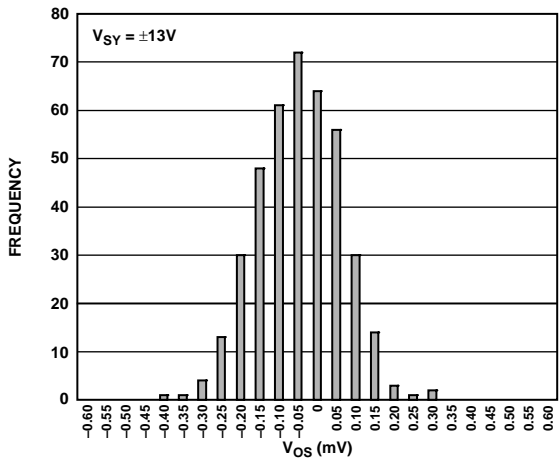


Figure 5. Input Offset Voltage

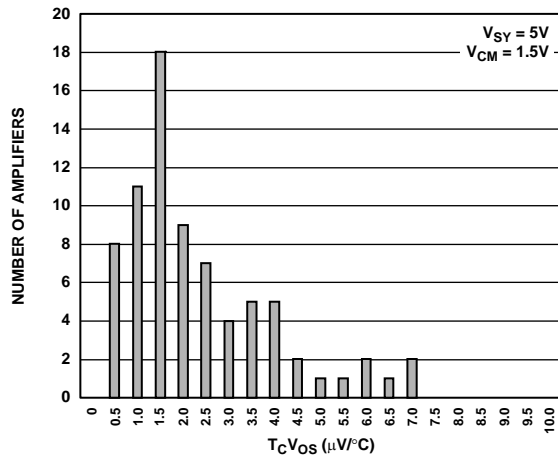


Figure 8. Offset Voltage Drift

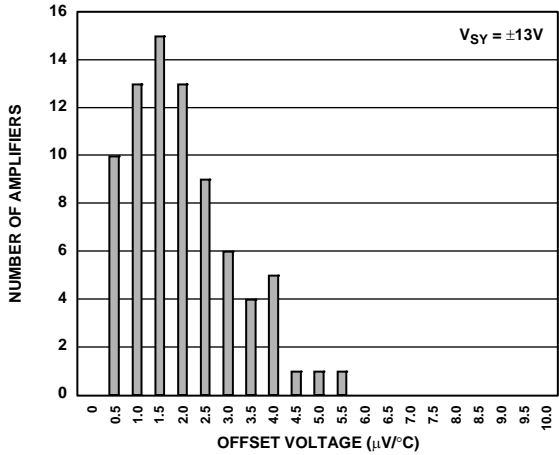


Figure 6. Offset Voltage Drift

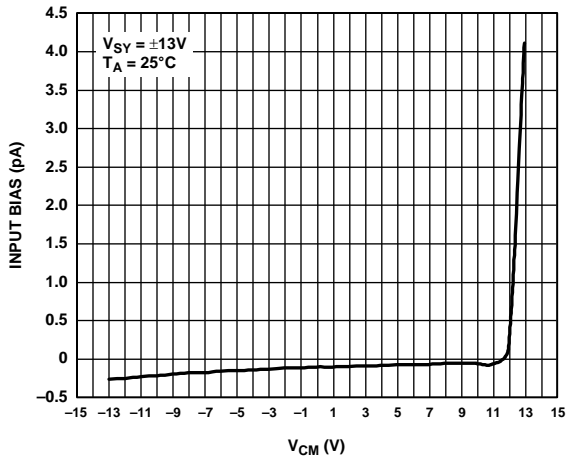


Figure 9. Input Bias Current vs.  $V_{CM}$

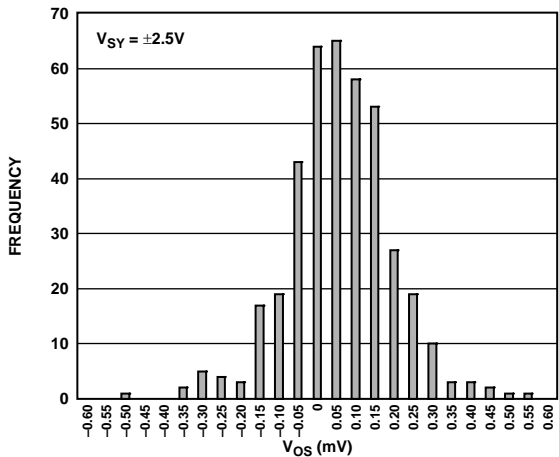


Figure 7. Input Offset Voltage

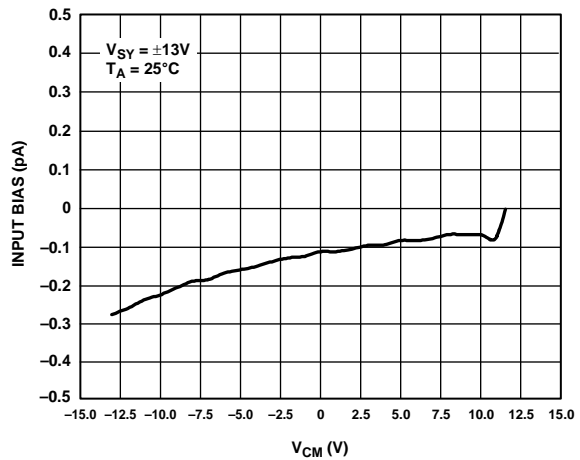


Figure 10. Input Bias Current vs.  $V_{CM}$

05072-002

05072-005

05072-003

05072-006

05072-004

05072-007

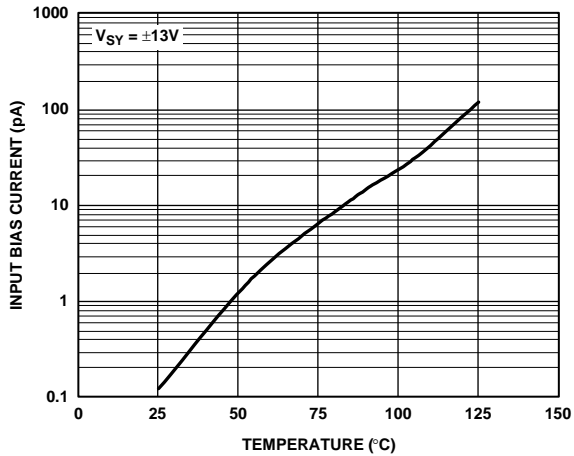


Figure 11. Input Bias Current vs. Temperature

05072-008

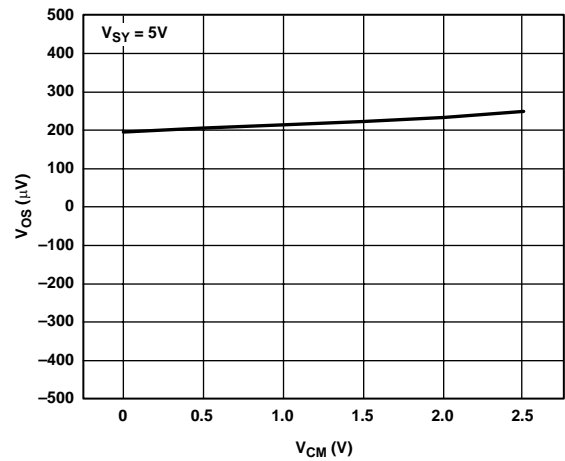


Figure 14. Input Offset Voltage vs.  $V_{CM}$

05072-011

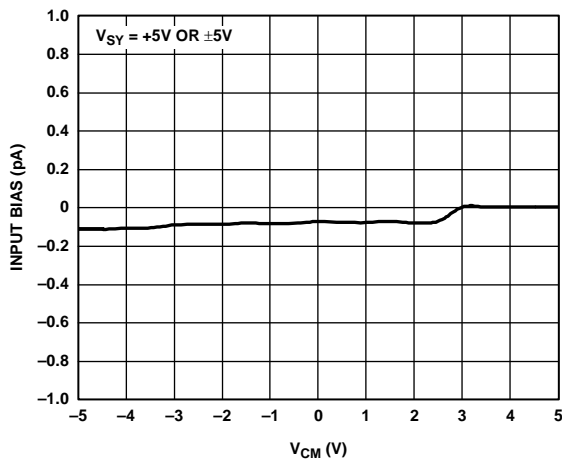


Figure 12. Input Bias Current vs.  $V_{CM}$

05072-009

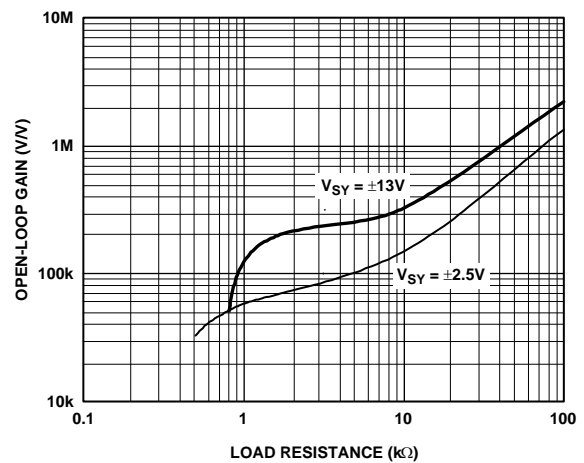


Figure 15. Open-Loop Gain vs. Load Resistance

05072-012

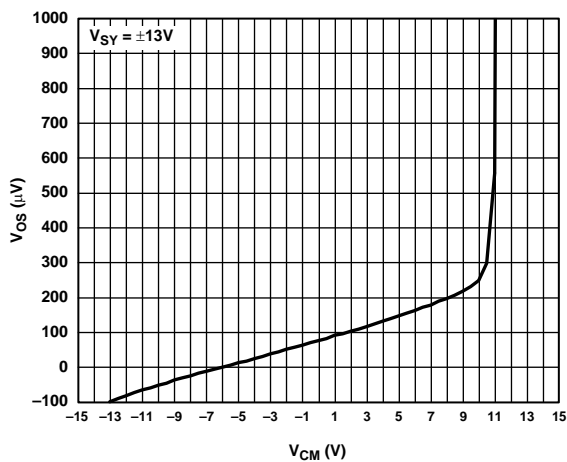


Figure 13. Input Offset Voltage vs.  $V_{CM}$

05072-010

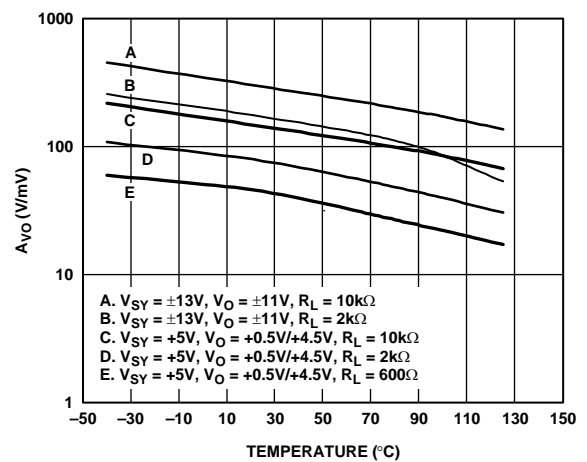


Figure 16. Open-Loop Gain vs. Temperature

05072-013

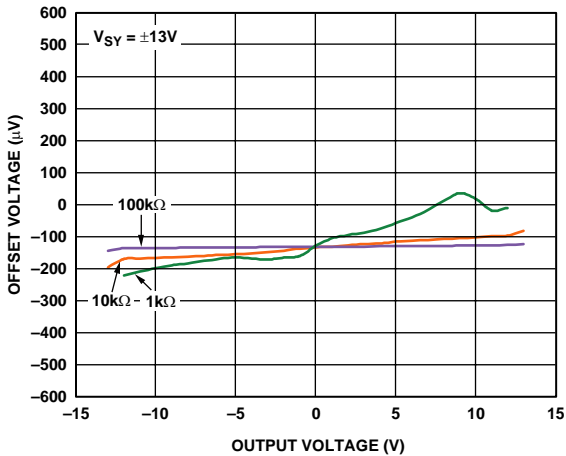


Figure 17. Input Error Voltage vs. Output Voltage for Resistive Loads

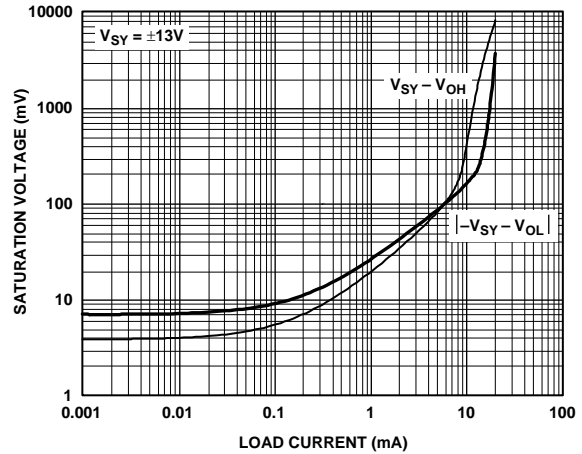


Figure 20. Output Saturation Voltage vs. Load Current

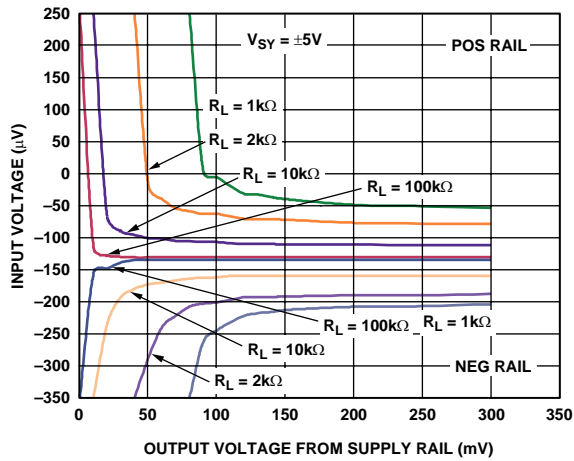


Figure 18. Input Error Voltage vs. Output Voltage Within 300 mV of Supply Rails

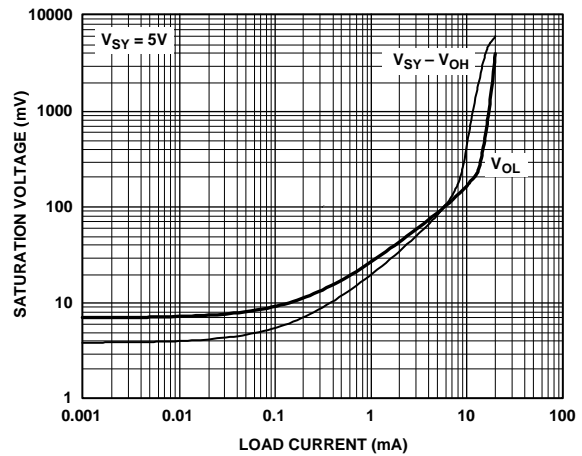


Figure 21. Output Saturation Voltage vs. Load Current

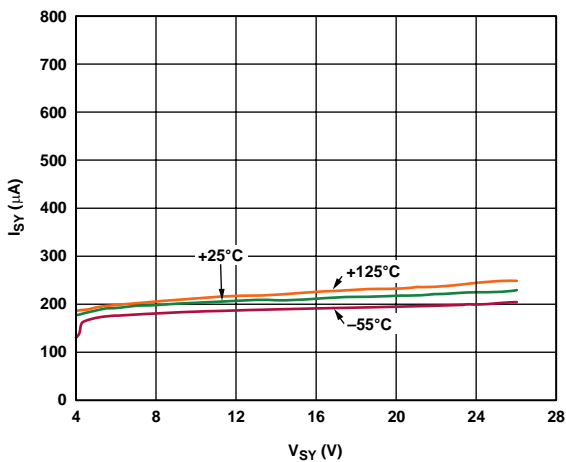


Figure 19. Quiescent Current vs. Supply Voltage at Different Temperatures

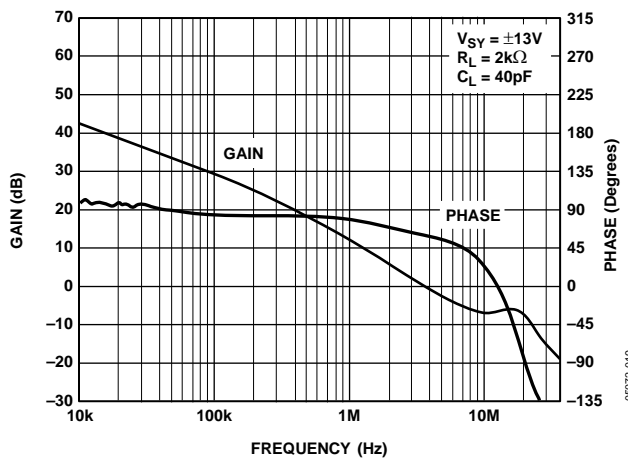


Figure 22. Open-Loop Gain and Phase Margin vs. Frequency



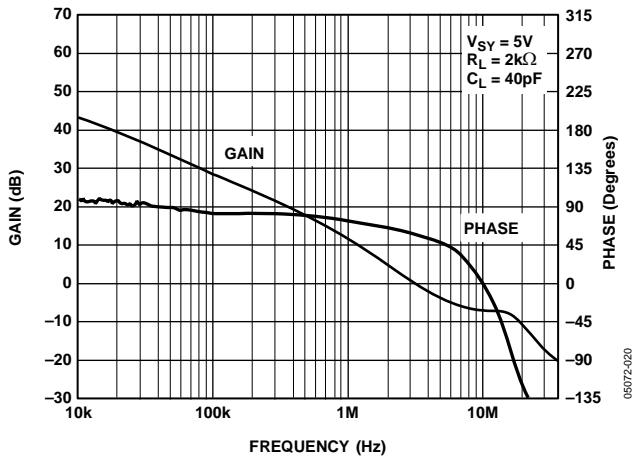


Figure 23. Open-Loop Gain and Phase Margin vs. Frequency

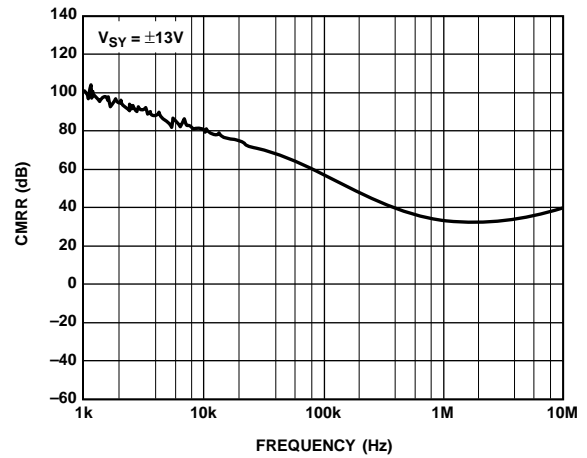


Figure 26. CMRR vs. Frequency

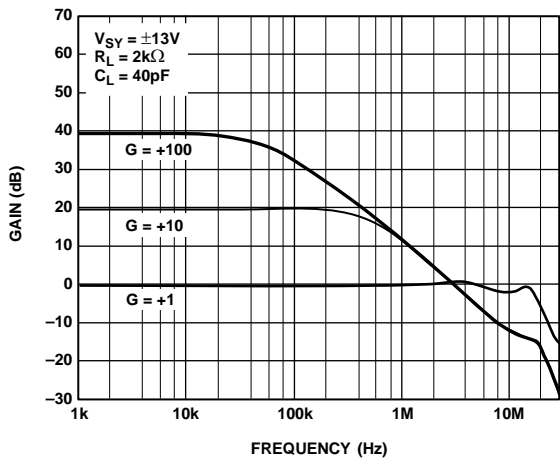


Figure 24. Closed-Loop Gain vs. Frequency

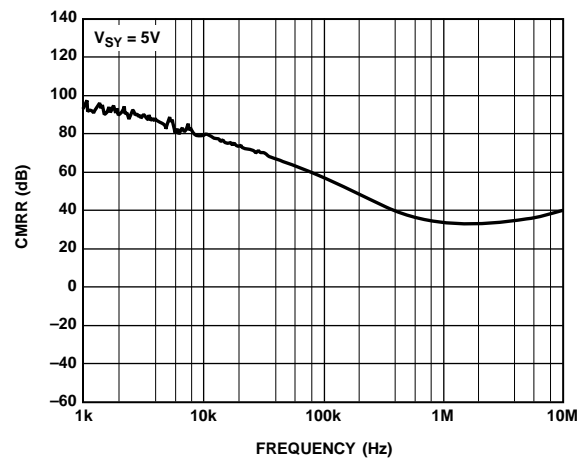


Figure 27. CMRR vs. Frequency

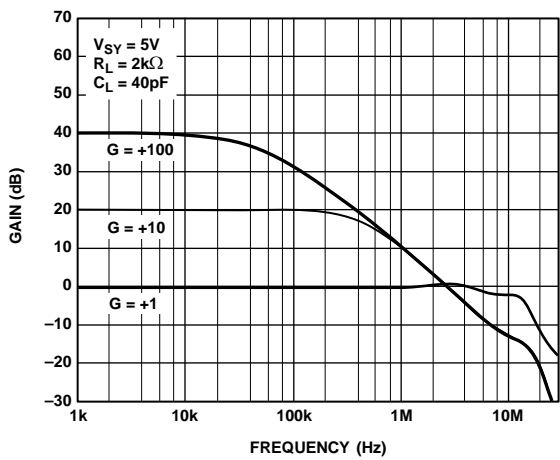


Figure 25. Closed-Loop Gain vs. Frequency

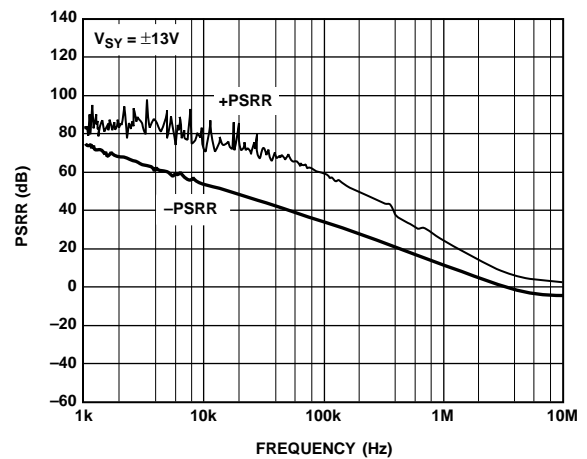


Figure 28. PSRR vs. Frequency

# AD8641/AD8642

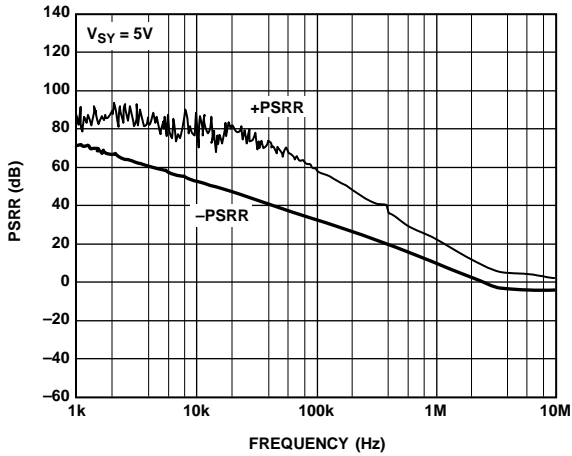


Figure 29. PSRR vs. Frequency

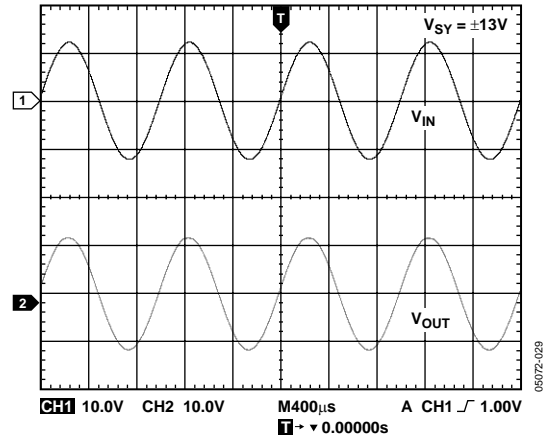


Figure 32. No Phase Reversal

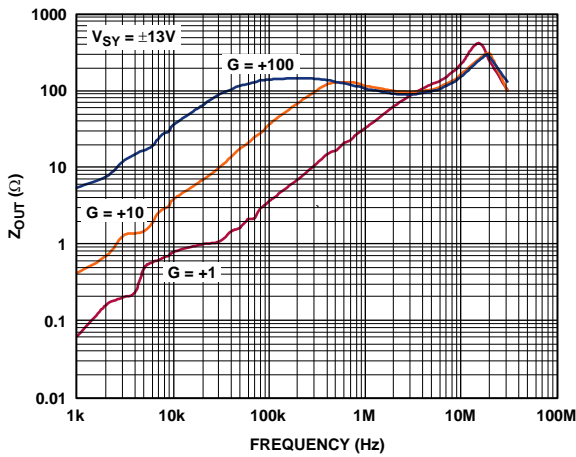


Figure 30. Output Impedance vs. Frequency

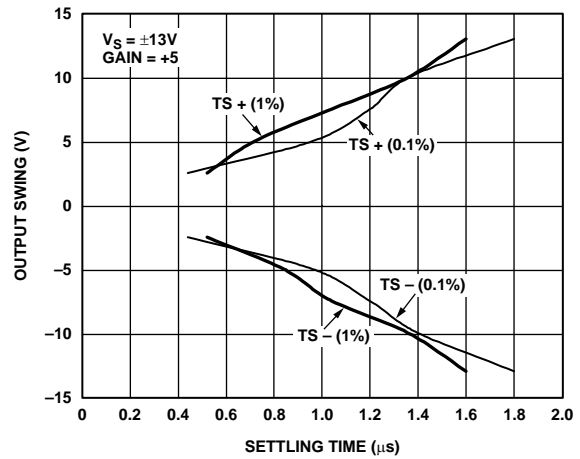


Figure 33. Output Swing and Error vs. Settling Time

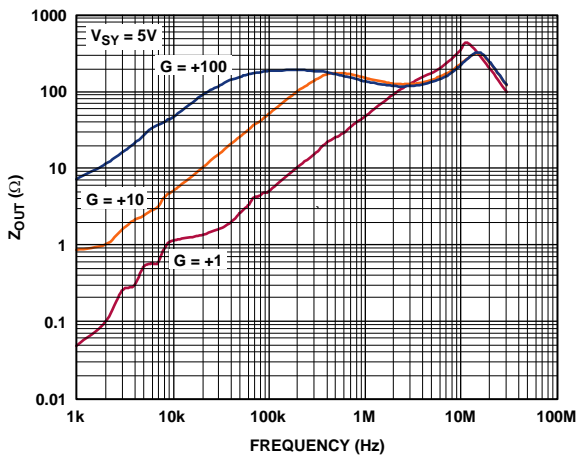


Figure 31. Output Impedance vs. Frequency

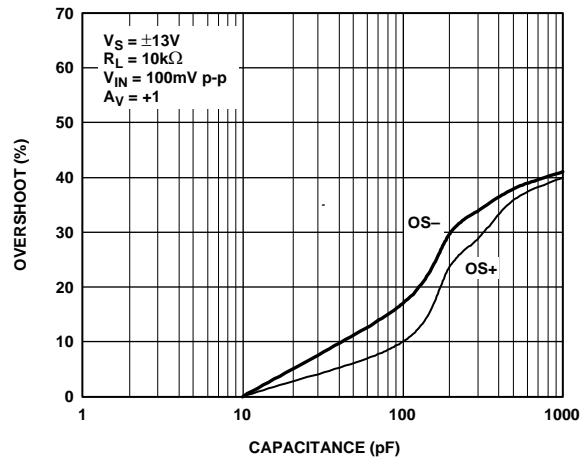


Figure 34. Small Signal Overshoot vs. Load Capacitance

05072-026

05072-027

05072-028

05072-029

05072-030

05072-031

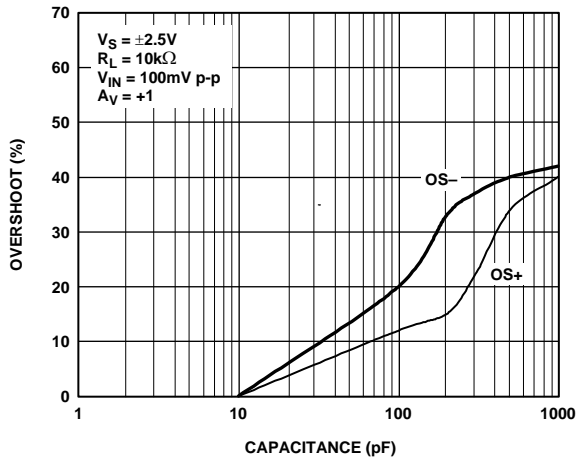


Figure 35. Small Signal Overshoot vs. Load Capacitance

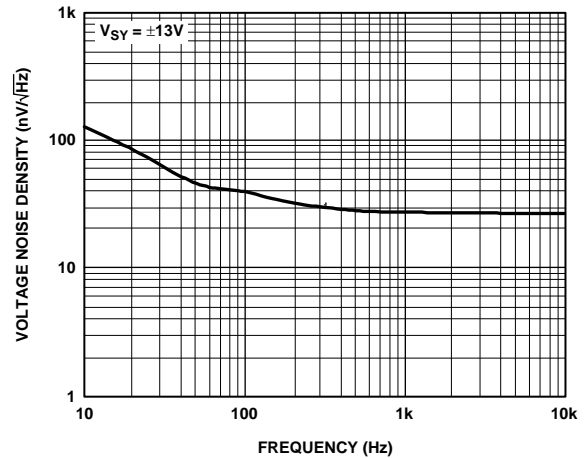


Figure 38. Voltage Noise Density

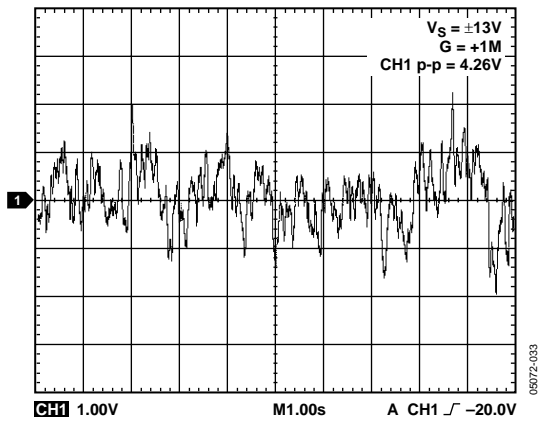


Figure 36. 0.1 Hz to 10 Hz Noise

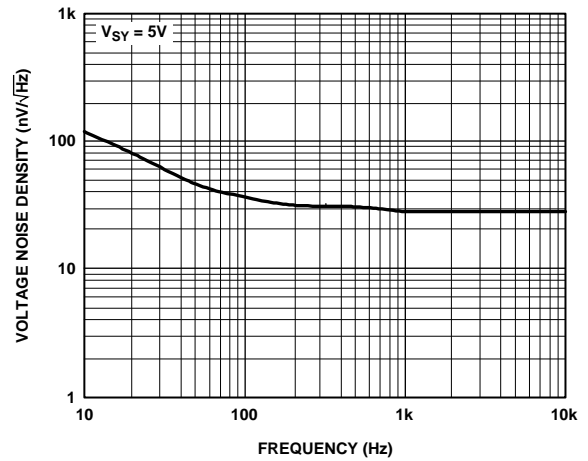


Figure 39. Voltage Noise Density

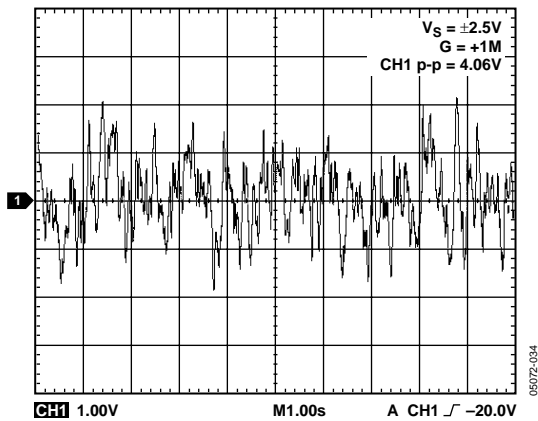


Figure 37. 0.1 Hz to 10 Hz Noise

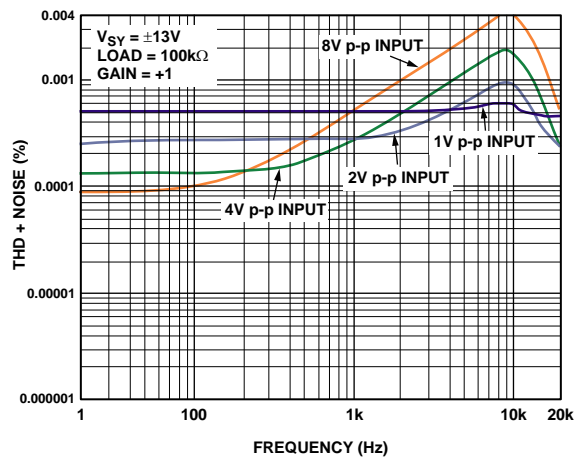


Figure 40. Total Harmonic Distortion + Noise vs. Frequency

# AD8641/AD8642

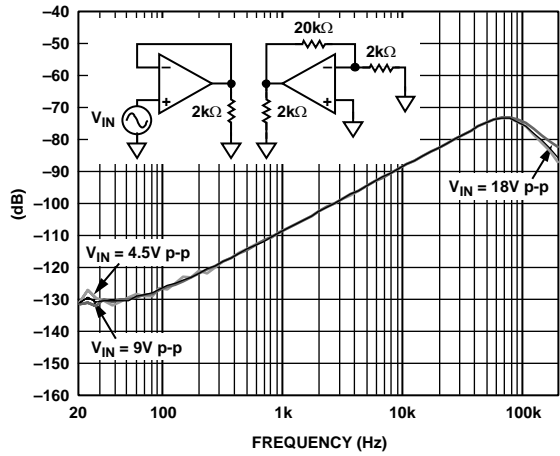
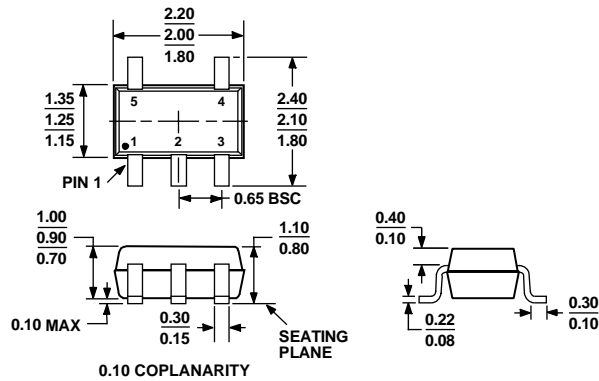


Figure 41. Channel Separation

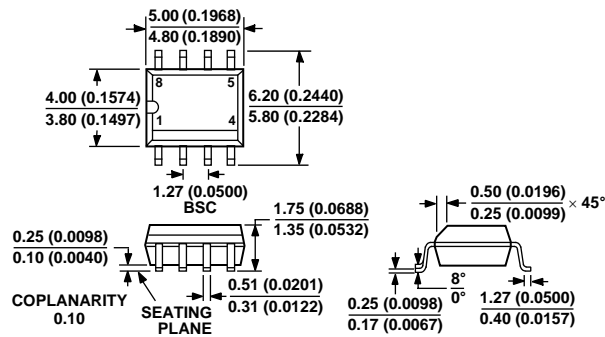
# OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-203AA

Figure 42. 5-Lead Thin Shrink Small Outline Transistor Package [SC70] (KS-5)

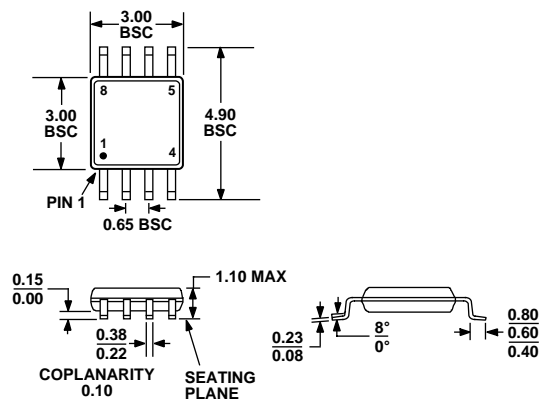
Dimensions shown in millimeters



COMPLIANT TO JEDEC STANDARDS MS-012-AA  
CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN

Figure 43. 8-Lead Standard Small Outline Package [SOIC\_N] (R-8)

Dimensions shown in millimeters and (inches)



COMPLIANT TO JEDEC STANDARDS MO-187-AA

Figure 44. 8-Lead Mini Small Outline Package [MSOP] (RM-8)

Dimensions shown in millimeters

# AD8641/AD8642

## ORDERING GUIDE

| Model                         | Temperature Range | Package Description | Package Option | Branding |
|-------------------------------|-------------------|---------------------|----------------|----------|
| AD8641AKSZ-R2 <sup>1</sup>    | -40°C to +125°C   | 5-Lead SC70         | KS-5           | A07      |
| AD8641AKSZ-REEL7 <sup>1</sup> | -40°C to +125°C   | 5-Lead SC70         | KS-5           | A07      |
| AD8641AKSZ-REEL <sup>1</sup>  | -40°C to +125°C   | 5-Lead SC70         | KS-5           | A07      |
| AD8641ARZ <sup>1</sup>        | -40°C to +125°C   | 8-lead SOIC_N       | R-8            |          |
| AD8641ARZ-REEL7 <sup>1</sup>  | -40°C to +125°C   | 8-lead SOIC_N       | R-8            |          |
| AD8641ARZ-REEL <sup>1</sup>   | -40°C to +125°C   | 8-lead SOIC_N       | R-8            |          |
| AD8642ARMZ-R2 <sup>1</sup>    | -40°C to +125°C   | 8-lead MSOP         | RM-8           | A0A      |
| AD8642ARMZ-REEL <sup>1</sup>  | -40°C to +125°C   | 8-lead MSOP         | RM-8           | A0A      |
| AD8642ARZ <sup>1</sup>        | -40°C to +125°C   | 8-lead SOIC         | R-8            |          |
| AD8642ARZ-REEL7 <sup>1</sup>  | -40°C to +125°C   | 8-lead SOIC         | R-8            |          |
| AD8642ARZ-REEL <sup>1</sup>   | -40°C to +125°C   | 8-lead SOIC         | R-8            |          |

<sup>1</sup> Z = Pb-free part.

**NOTES**

**AD8641/AD8642**

**NOTES**